

PC417

**Compact, Surface Mount
Ultra-high Speed Response
OPIC Photocoupler**

■ Features

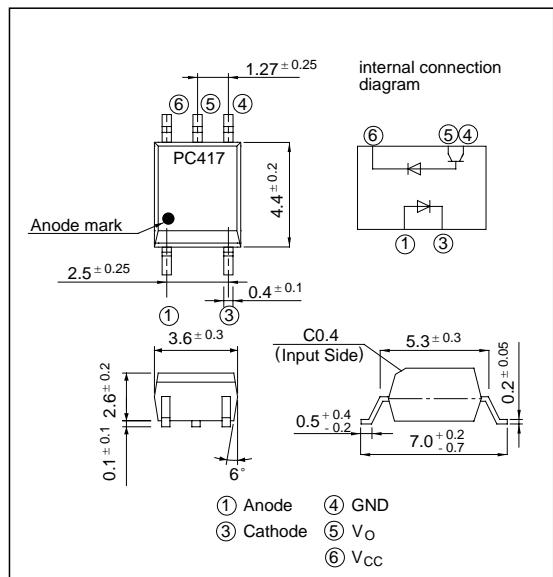
1. Mini-flat package
2. Ultra-high speed response
(t_{PHL}, t_{PLH} : TYP. $0.3\ \mu s$ at $R_L = 1.9k\Omega$)
3. Isolation voltage between input and output
($V_{iso} : 2\ 500\ V_{rms}$)
4. High instantaneous common mode rejection voltage (CM_H : TYP. $1\ kV/\ \mu s$)
5. Recognized by UL(No.64380)

■ Applications

1. Hybrid substrate which requires high density mounting
2. Personal computers, office computers and peripheral equipment
3. Audio equipment

■ Outline Dimensions

(Unit : mm)



■ Package Specifications

Model No.	Package specifications	Diameter of reel	Tape width
PC417	Taping package (Net:3 000pcs.)	$\phi\ 370\text{mm}$	12mm
PC417T	Taping package (Net: 750pcs.)	$\phi\ 178\text{mm}$	12mm
PC417Z	Sleeve package (Net: 100pcs.)	-	-

■ Absolute Maximum Ratings

(Ta = 25°C)

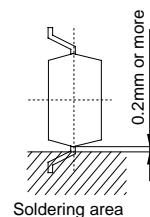
	Parameter	Symbol	Rating	Unit
Input	* ¹ Forward current	I _F	25	mA
	Reverse voltage	V _R	5	V
	Power dissipation	P	45	mW
Output	* ² Supply voltage	V _{CC}	- 0.5 to + 15	V
	Output voltage	V _O	- 0.5 to + 15	V
	Output current	I _O	8	mA
	Power dissipation	P _O	100	mW
Total power dissipation		P _{tot}	100	mW
* ³	Isolation voltage	V _{iso}	2 500	V _{rms}
Operating temperature		T _{opr}	- 40 to + 100	°C
Storage temperature		T _{stg}	- 40 to + 125	°C
* ⁴	Soldering temperature	T _{sol}	260	°C

*1 Ta = 0 to + 70°C

*2 For 1 minute max.

*3 40 to 60% RH, For AC 1 minute, Apply the specified voltage between the whole of the electrode pins on the input side and the whole of the electrode pins on the output side.

*4 For 10 seconds.



■ Electro-optical Characteristics

(Ta= 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 16mA	-	1.7	1.95	V
	Reverse current	I _R	V _R = 5V	-	-	10	μA
	Terminal capacitance	C _t	V _F = 0, f= 1MHz	-	60	250	pF
Output	High level output current	I _{OH(1)}	I _F =0, V _{CC} =5.5V V _O =5.5V	-	3	500	nA
		I _{OH(2)}	I _F =0, V _{CC} =15V, V _O =15V	-	-	1.0	μA
		I _{OH(3)}	I _F =0, V _{CC} =15V, V _O =15V *5	-	-	50	μA
	High level supply current	I _{CCH(1)}	I _F =0, V _{CC} =15V, V _O =OPEN	-	0.02	1.0	μA
		I _{CCH(2)}	I _F =0, V _{CC} =15V, V _O =OPEN *5	-	-	2.0	
	Low level supply current	I _{CCL}	I _F =16mA, V _{CC} =15V V _O =OPEN *5	-	200	-	μA
	Low level output voltage	V _{OL}	I _F =16mA, V _{CC} =4.5V I _O =2.4mA *5	-	-	0.4	V
Transfer characteristics	Current transfer ratio	CTR	I _F =16mA, V _{CC} =4.5V V _O =0.4V *5	19	-	-	%
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance	C _f	V=0V, f=1MHz	-	0.6	1.0	pF
	*6 "H→L" propagation delay time	t _{PHL}	I _F =16mA, V _{CC} =5V	-	0.3	0.8	μs
	*6 "L→H" propagation delay time	t _{PLH}		-	0.3	1.2	
	*7 Instantaneous common mode rejection voltage "High level output"	CM _H	I _F =0, R _L =1.9kΩ V _{CM} =10V _{P-P} , V _{CC} =5V	-	1 000	-	V/ μs
	*7 Instantaneous common mode rejection voltage "Low level output"	CM _L	I _F =16mA, R _L =1.9kΩ V _{CM} =10V _{P-P} , V _{CC} =5V	-	- 1 000	-	V/ μs

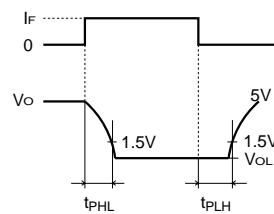
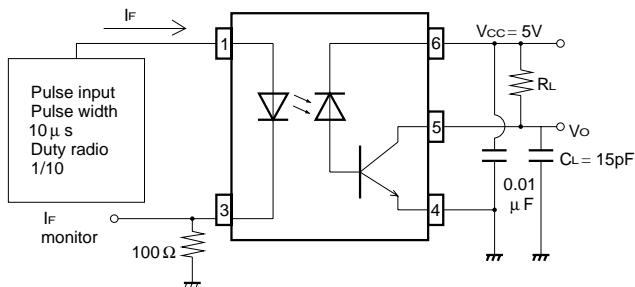
*5 Temperature range : Ta = 0 to 70°C

*6 Test circuit for propagation delay time is shown in the next page.

*7 Test circuit for instantaneous common mode rejection voltage is shown in the next page.

Each characteristics shall be measured under opaque condition.

*6 Test Circuit for Propagation Delay Time



*7 Test Circuit for Instantaneous Common Mode Rejection Voltage

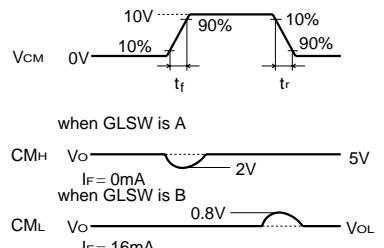
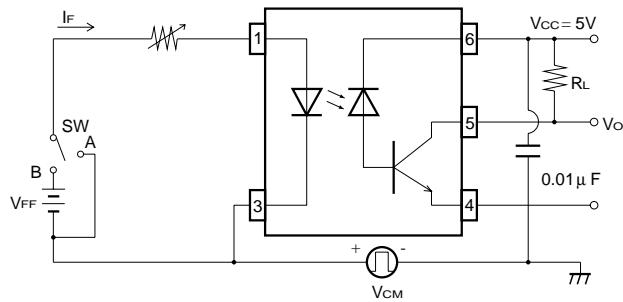


Fig. 1 Forward Current vs. Ambient Temperature

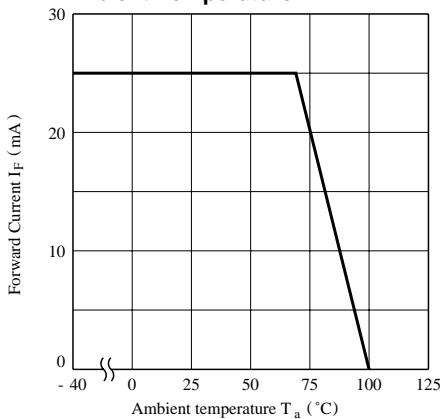
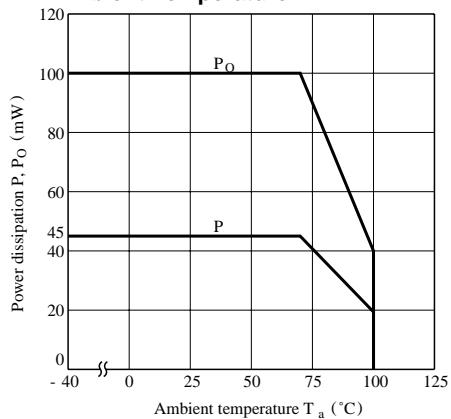
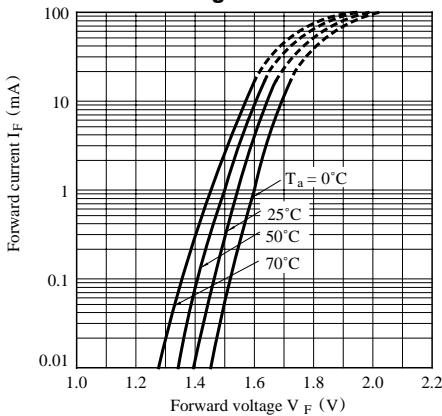


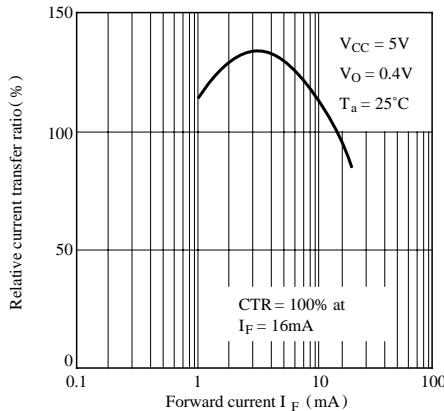
Fig. 2 Power Dissipation vs. Ambient Temperature



**Fig. 3 Forward Current vs.
Forward Voltage**



**Fig. 5 Relative Current Transfer Ratio vs.
Forward Current**



**Fig. 7 Propagation Delay Time vs.
Ambient Temperature**

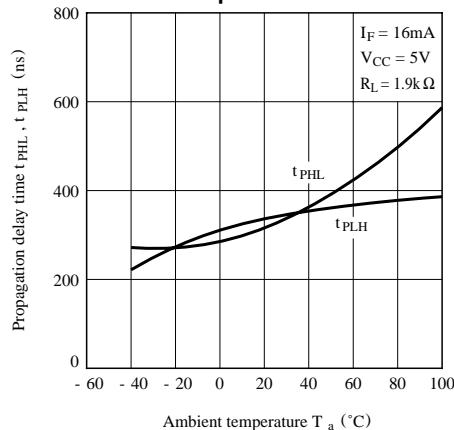
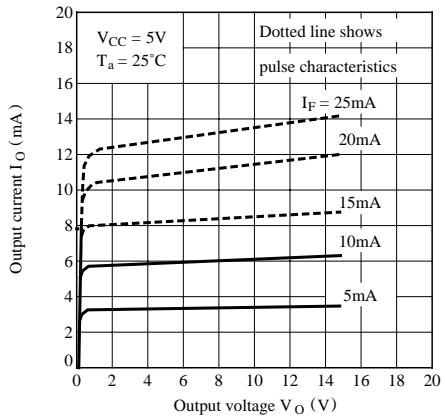
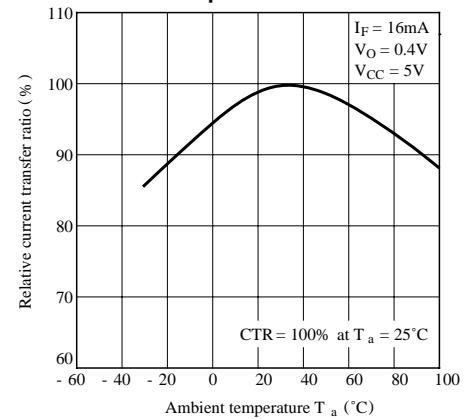


Fig. 4 Output Current vs. Output Voltage



**Fig. 6 Relative Current Transfer Ratio vs.
Ambient Temperature**



**Fig. 8 High Level Output Current vs.
Ambient Temperature**

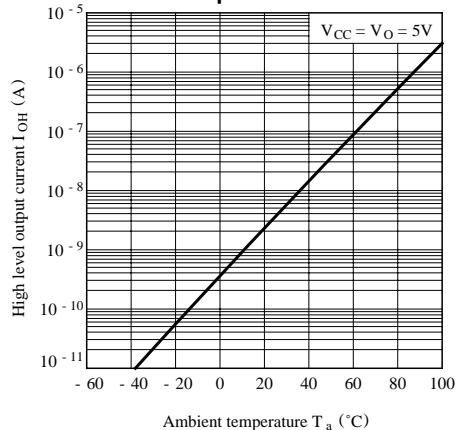
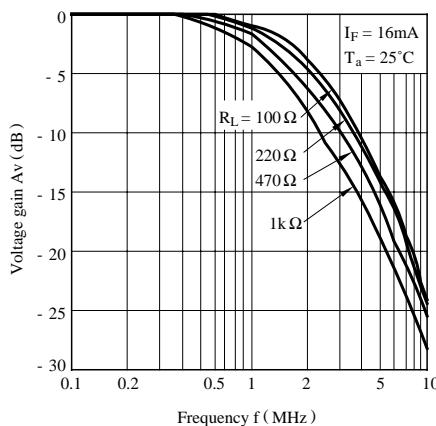
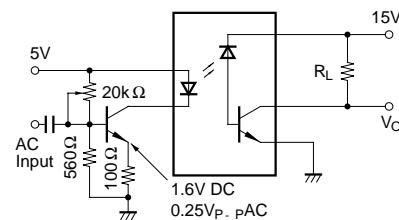


Fig. 9 Frequency Response**Test Circuit for Frequency Response**

■ Precautions for Use

- (1) It is recommended that a by-pass capacitor of more than $0.01\mu F$ be added between V_{cc} and GND near the device in order to stabilize power supply line.
- (2) Transistor of detector side in bipolar configuration is apt to be affected by static electricity for its minute design. When handling them, general counterplan against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.
- (3) As for other general cautions, refer to the chapter "Precautions for Use"